TOSHIBA Diode Silicon Epitaxial Planar Type

# **JDV2S05S**

#### VCO for UHF band

• High capacitance ratio:  $C_{1V}/C_{4V} = 1.9$  (typ.)

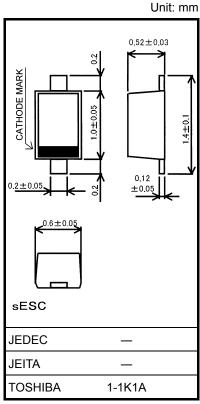
- Low series resistance:  $r_s = 0.3 \Omega$  (typ.)
- This device is suitable for use in a small-size tuner.

## Absolute Maximum Ratings (Ta = 25°C)

| Characteristics           | Symbol           | Rating  | Unit |
|---------------------------|------------------|---------|------|
| Reverse voltage           | $V_{R}$          | 10      | ٧    |
| Junction temperature      | Tj               | 150     | °C   |
| Storage temperature range | T <sub>stg</sub> | -55~150 | °C   |

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).



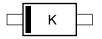
Weight: 0.0011 g (typ.)

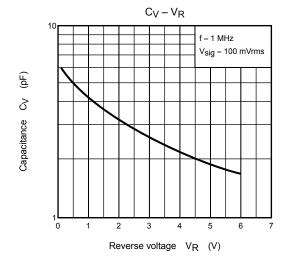
## **Electrical Characteristics (Ta = 25°C)**

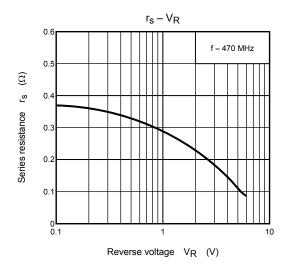
| Characteristics   | Symbol                           | Test Condition                    | Min  | Тур. | Max  | Unit |
|-------------------|----------------------------------|-----------------------------------|------|------|------|------|
| Reverse voltage   | $V_{R}$                          | $I_R = 1 \mu A$                   | 10   | _    | _    | V    |
| Reverse current   | I <sub>R</sub>                   | V <sub>R</sub> = 10 V             | _    | _    | 3    | nA   |
| Capacitance       | C <sub>1V</sub>                  | V <sub>R</sub> = 1 V, f = 1 MHz   | 3.85 | 4.2  | 4.55 | - pF |
|                   | C <sub>4V</sub>                  | V <sub>R</sub> = 4 V, f = 1 MHz   | 1.94 | 2.2  | 2.48 |      |
| Capacitance ratio | C <sub>1V</sub> /C <sub>4V</sub> | _                                 | 1.7  | 1.9  | _    | _    |
| Series resistance | r <sub>S</sub>                   | V <sub>R</sub> = 1 V, f = 470 MHz | _    | 0.3  | 0.5  | Ω    |

Note: Signal level when capacitance is measured.  $V_{sig} = 100 \text{ mVrms}$ 

## Marking







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#### **RESTRICTIONS ON PRODUCT USE**

20070701-EN GENERAL

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